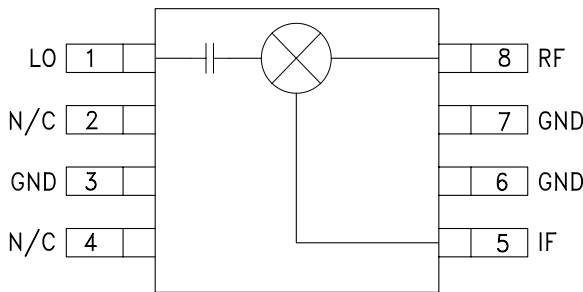


### Typical Applications

High Dynamic Range Infrastructure:

- GSM, GPRS & EDGE
- CDMA & W-CDMA
- Cable Modem Termination Systems

### Functional Diagram



### Features

- +35 dBm Input IP3
- Conversion Loss: 8.5 dB
- Low External Part Count
- Ultra Small MSOP8 Package: 14.8 mm<sup>2</sup>

### General Description

The HMC399MS8 is a high dynamic range passive MMIC mixer in a plastic surface mount 8 lead Mini Small Outline Package (MSOP) covering 700 to 1000 MHz. Excellent input IP3 performance of +35 dBm for down conversion and +32 dBm for up conversion is provided for 2.5G & 3G GSM/CDMA based cellular applications at an LO drive of +17dBm. With a 1 dB compression of +23 dBm, the RF port will accept a wide range of input signal levels. Conversion loss is 8.5 dB typical and LO isolations are maintained at 23 to 35 dB. This miniature single-ended monolithic GaAs FET mixer requires only one external inductor to optimize the LO frequency response. The 50 to 250 MHz IF frequency response will satisfy many cellular transmit or receive frequency plans. The HMC399MS8 input IP3 performance coupled with its high P1dB rivals traditional active FET mixers while offering a much smaller 14.8mm<sup>2</sup> standard IC footprint and no DC bias.

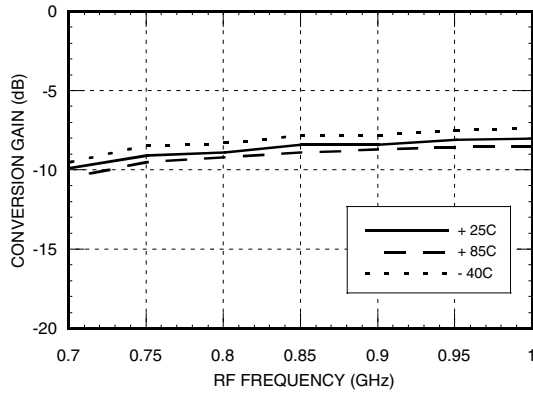
### Electrical Specifications, $T_A = +25^\circ\text{C}$ , LO = +17 dBm, IF = 200 MHz\*

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range, RF		740 - 800		800 - 900			880 - 960			MHz
Frequency Range, LO**		540 - 740		550 - 840			630 - 900			MHz
Frequency Range, IF		DC - 200		DC - 250			DC - 250			MHz
Conversion Loss		9	10		8.5	9.5		8	10	dB
Noise Figure (SSB)		9	10		8.5	9.5		8	10	dB
LO to RF Isolation	19	23		20	24		21	25		dB
LO to IF Isolation	22	27		26	31		29	35		dB
IP3 (Input)	30	34		31	35		30	34		dBm
1 dB Gain Compression (Input)	20	24		19	23		18	22		dBm
LO Input Drive Level (Typical)		+16 to +18		+16 to +18			+16 to +18			dBm

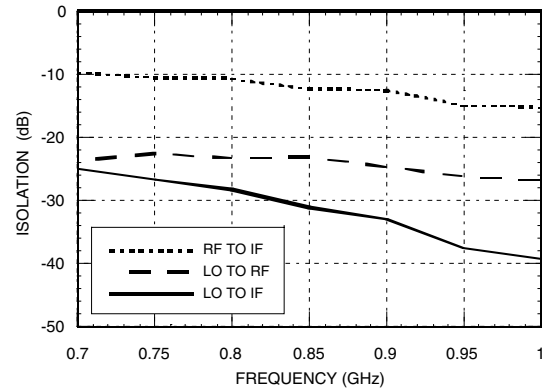
\* Unless otherwise noted, all measurements performed as a downconverter with low side LO & IF = 200 MHz

\*\* LO Frequency optimized. See application circuit herein.

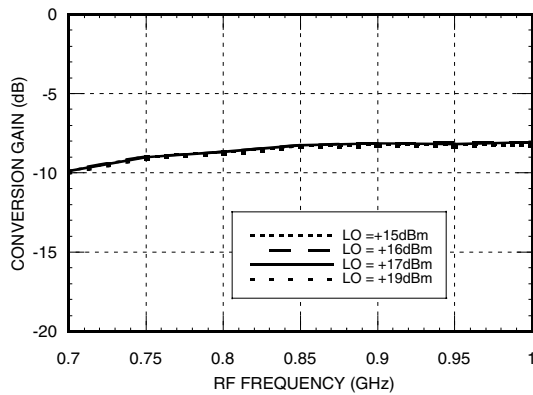
**Conversion Gain vs.  
Temperature @ LO = +17 dBm**



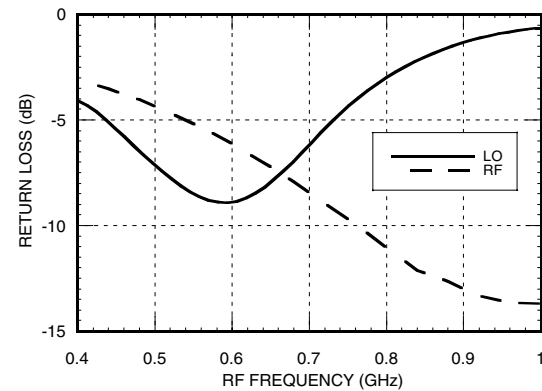
**Isolation @ LO = +17 dBm**



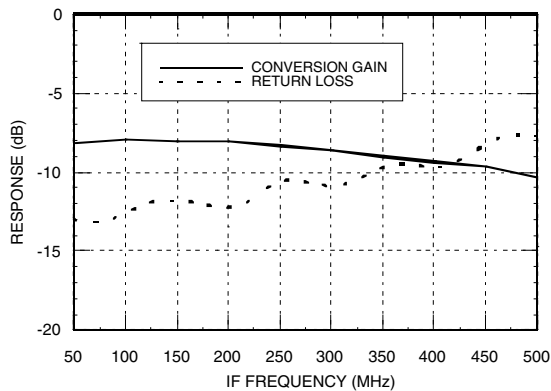
**Conversion Gain vs. LO Drive**



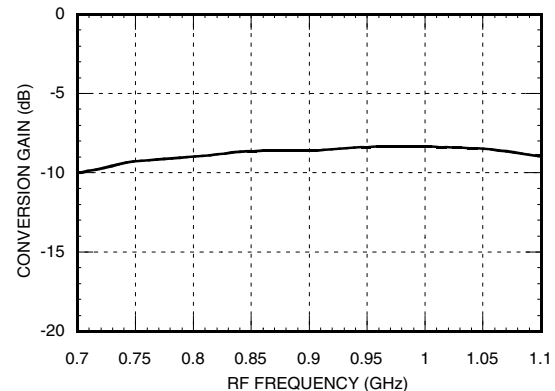
**Return Loss @ LO = +17 dBm\***



**If Bandwidth @ LO = +17 dBm**



**Upconverter Conversion Gain  
@ LO = +17 dBm**

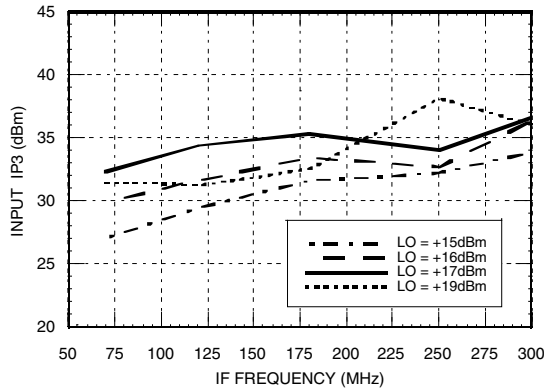


\* Unless otherwise noted, all measurements performed as a downconverter with low side LO & IF = 200 MHz

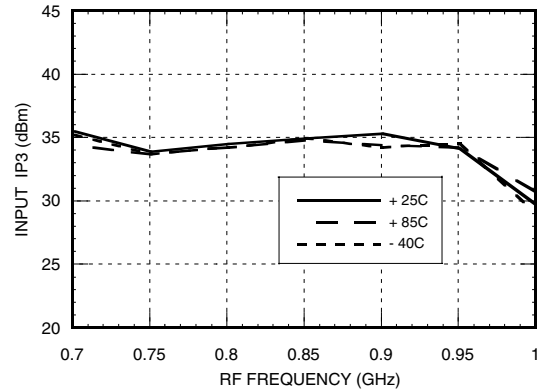
\*\* LO Frequency optimized. See application circuit herein.

## HIGH IP3 GaAs MMIC MIXER, 700 - 1000 MHz

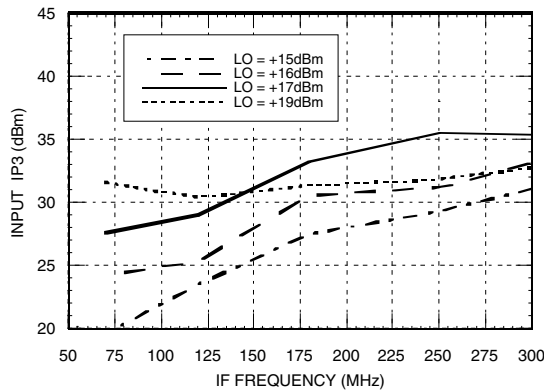
**Input IP3 vs. IF Frequency, RF = 850 MHz**



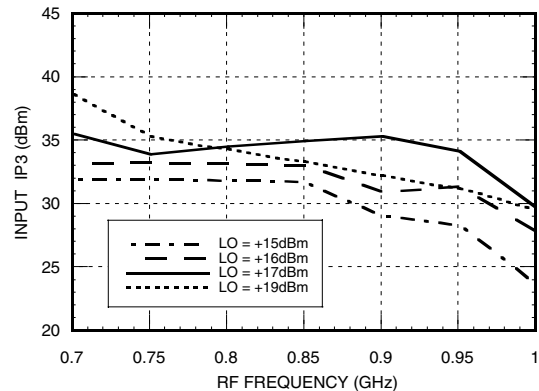
**Input IP3 vs. Temperature @ LO = +17 dBm**



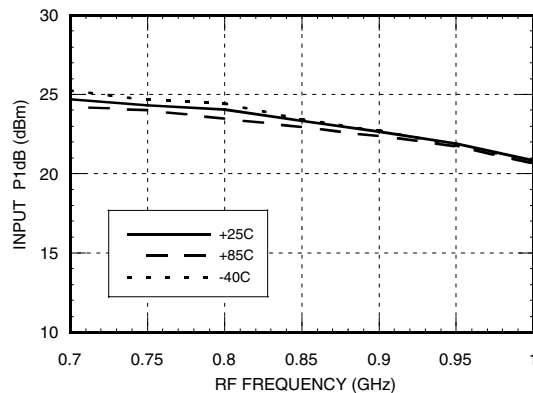
**Input IP3 vs. IF Frequency, RF = 950 MHz**



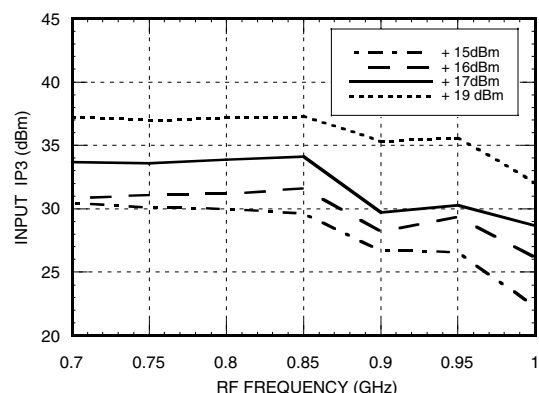
**Input IP3 vs. LO Drive**



**Input P1dB vs. Temperature @ LO = +17 dBm**



**Upconverter Input IP3 vs. LO Drive**



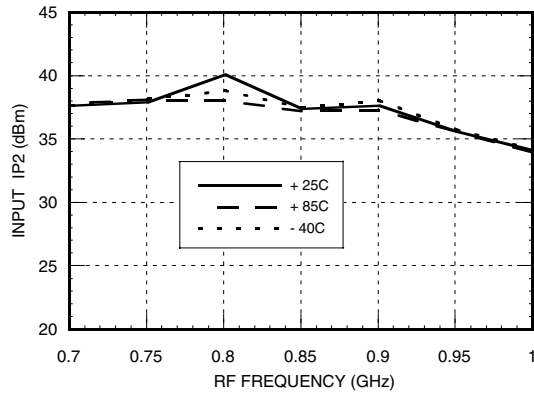
\* Unless otherwise noted, all measurements performed as a downconverter with low side LO & IF = 200 MHz

\*\* LO Frequency optimized. See application circuit herein.

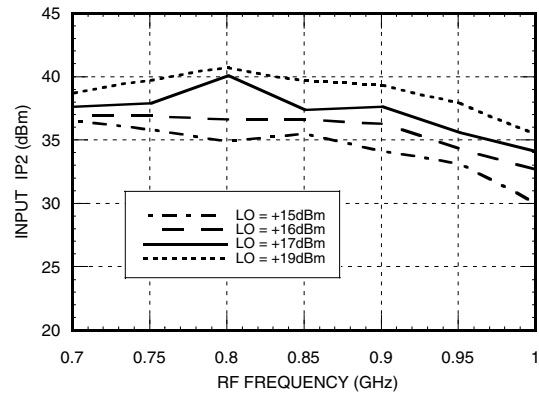
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## HIGH IP3 GaAs MMIC MIXER, 700 - 1000 MHz

**Input IP2 vs. Temperature @ LO = +17 dBm**



**Input IP2 vs. LO Drive**



**MxN Spurious Outputs**

mRF	nLO				
	0	1	2	3	4
0	xx	-9	17	2	23
1	3	0	17	28	26
2	69	75	57	62	65
3	80	71	82	69	80
4	81	81	81	80	80

RF Freq = 0.801 GHz @ -10 dBm  
 LO Freq = 0.601 GHz @ +17 dBm  
 All values in dBc relative to the IF power level.

**Harmonics of LO**

LO Freq (GHz)	nLO Spur @ RF Port			
	1	2	3	4
0.4	34	54	38	45
0.5	30	39	35	47
0.6	26	35	33	54
0.7	24	37	36	47
0.8	23	33	42	50
0.9	25	31	46	43

LO = +17 dBm  
 All values are in dBc below input LO level @ RF port.

\* LO Frequency optimized. See application circuit herein.

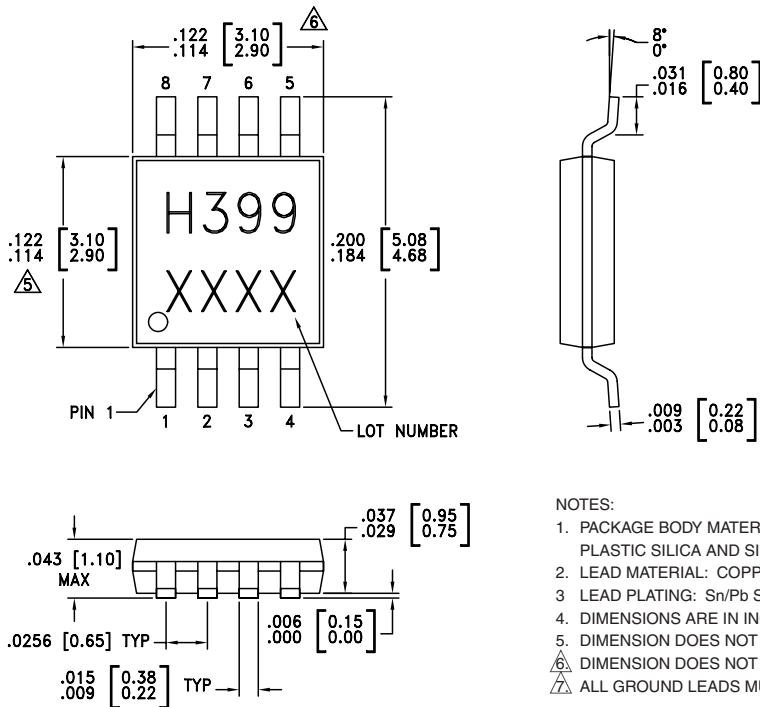
### Absolute Maximum Ratings

RF/IF Input	+25 dBm
LO Drive	+27 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
IF DC Current	±40 mA

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MIXERS - SMT

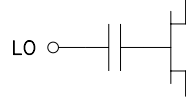

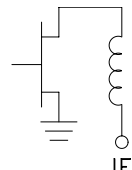
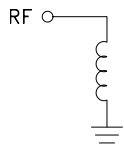
### Outline Drawing



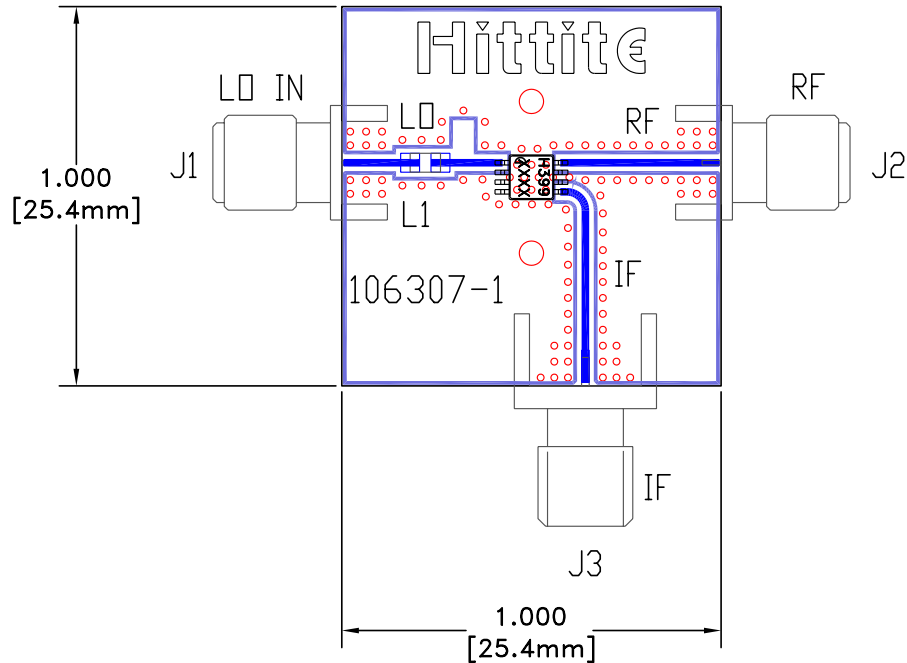
NOTES:

1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
  2. LEAD MATERIAL: COPPER ALLOY
  3. LEAD PLATING: Sn/Pb SOLDER
  4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
  5. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- ⚠ DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.  
 ⚠ ALL GROUND LEADS MUST BE SOLDERED TO THE PCB RF GROUND.

### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	LO	This pin is AC coupled & matched to 50 Ohms when an external inductor (L1) is connected in series with the LO. Choose value of L1 to optimize LO frequency response.	
2, 4	N/C	Not connected.	
3, 6, 7	GND	This pin must be connected to RF ground.	
5	IF Port	This pin is DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor. Choose value of C1 to pass IF frequency desired. For operation to DC, this pin must not sink/source more than 40 mA of current or failure may result.	
8	RF Port	This pin is DC coupled & matched to 50 Ohms from 700 - 1000 MHz	

### Evaluation PCB



### List of Material

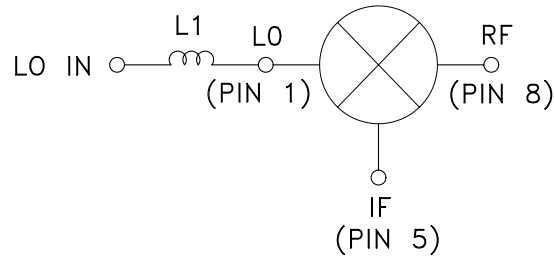
Item	Description
J1 - J3	PC Mount SMA RF Connector
L1*	24 nH Chip Inductor, 0805 Pkg
U1	HMC399MS8 Mixer
PCB*	106307 Eval Board
* Circuit Board Material: Rogers 4350	

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of VIA holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

\* Unless otherwise noted, all measurements performed as a downconverter with low side LO & IF = 200 MHz

\*\* LO Frequency optimized. See application circuit herein.

### Application Circuit



### Selection of L1 for Optimal LO Frequency $\pm 10\%$

Choose value of L1 to optimize LO Frequency response. For best results use an 0805 size RF inductor or smaller.

LO Frequency (MHz)	L1 (nH)
600	24

\* Unless otherwise noted, all measurements performed as a downconverter with low side LO & IF = 200 MHz

\*\* LO Frequency optimized. See application circuit herein.